74LVC2G38 Dual 2-input NAND gate; open drain Rev. 13 – 3 July 2017

Product data sheet

General description 1

The 74LVC2G38 provides a 2-input NAND function.

The outputs of the 74LVC2G38 devices are open-drain and can be connected to other open-drain outputs to implement active-LOW, wired-OR or active-HIGH wired-AND functions.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2 Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant outputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
- – JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
- HBM EIA/JESD22-A114F exceeds 2 000 V - MM EIA/JESD22-A115-A exceeds 200 V
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- · Open-drain outputs
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3 Ordering information

Table 1. Orderin	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74LVC2G38DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74LVC2G38DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74LVC2G38GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1
74LVC2G38GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm	SOT1089
74LVC2G38GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm	SOT902-2
74LVC2G38GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116
74LVC2G38GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203
74LVC2G38GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm	SOT1233

4 Marking

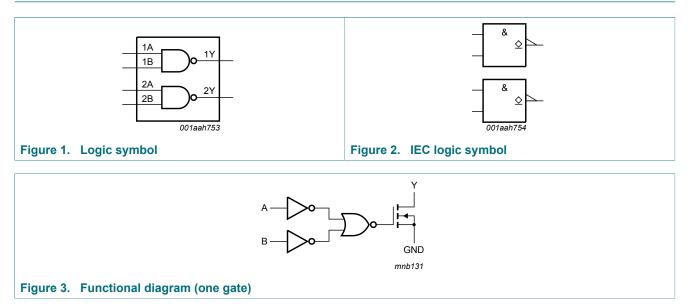
Table 2. Marking codes

Marking code ^[1]
Y38
Y38
Y38
YB
Y38
YB
ҮВ
YB

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

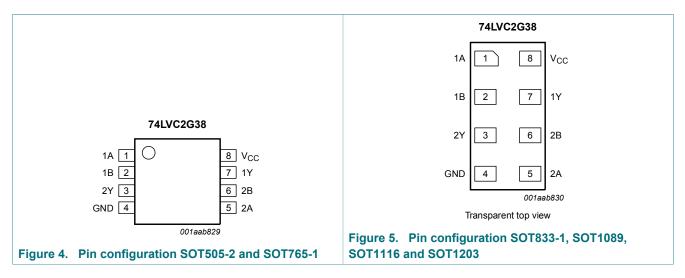
Dual 2-input NAND gate; open drain

5 Functional diagram

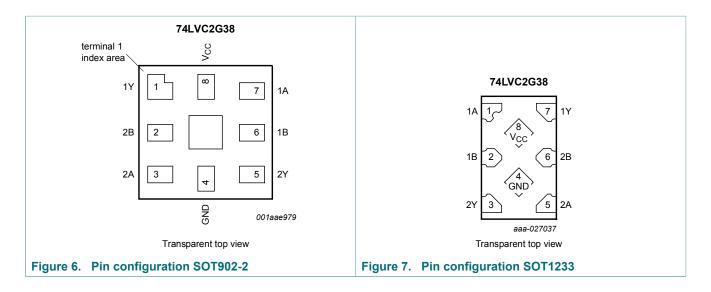


6 Pinning information

6.1 Pinning



Dual 2-input NAND gate; open drain



6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233	SOT902-2	_
1A, 2A	1, 5	7, 3	data input
1B, 2B	2, 6	6, 2	data input
GND	4	4	ground (0 V)
1Y, 2Y	7, 3	1, 5	data output
V _{CC}	8	8	supply voltage

7 Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

Input		Output
nA	nB	nY
L	L	Z
L	н	Z
н	L	Z
Н	Н	L

Limiting values 8

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
VI	input voltage		[1]	-0.5	+6.5	V
Vo	output voltage	Active mode	[1] [2]	-0.5	+6.5	V
		Power-down mode	[1] [2]	-0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
I _{ОК}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
I _O	output current	V_{O} = 0 V to V_{CC}		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[3]	-	300	mW

The input and output voltage ratings may be exceeded if the input and output current ratings are observed. [1]

When V_{CC} = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation. For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K. [2] [3] For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K. For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

For X2SON8 package: above 118 °C the value of Ptot derates linearly with 7.7 mW/K.

Recommended operating conditions 9

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		1.65	5.5	V
VI	input voltage		0	5.5	V
V _o	output voltage	Active mode	0	V _{CC}	V
		disable mode	0	5.5	V
		Power-down mode	0	5.5	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	20	ns/V
		V_{CC} = 2.7 V to 5.5 V	-	10	ns/V

10 Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ ^[1]	Мах	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V_{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 100 $\mu\text{A};$ V_{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	0.08	0.45	V
		$I_{\rm O}$ = 8 mA; $V_{\rm CC}$ = 2.3 V	-	0.14	0.3	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	0.19	0.4	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	0.37	0.55	V
		I_{O} = 32 mA; V_{CC} = 4.5 V	-	0.43	0.55	V
lı	input leakage current	V_{I} = 5.5 V or GND; V_{CC} = 0 V to 5.5 V	-	±0.1	±1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 5.5 \text{ V}$	-	±0.1	±2	μA
I _{OFF}	power-off leakage current	$V_1 \text{ or } V_0 = 5.5 \text{ V}; V_{CC} = 0 \text{ V}$	-	±0.1	±2	μA
I _{CC}	supply current	V_{I} = 5.5 V or GND; V_{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	0.1	4	μA
ΔI _{CC}	additional supply current	per pin; V _I = V _{CC} - 0.6 V; V _{CC} = 2.3 V to 5.5 V; I _O = 0 A	-	5	500	μA
Cı	input capacitance		-	2.5	-	pF

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Dual 2-input NAND gate; open drain

Symbol	Parameter	Conditions	Min	Typ ^[1]	Мах	Unit
T _{amb} = -4	0 °C to +125 °C			1	1	
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 100 $\mu\text{A};$ V_{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.70	V
		I_{O} = 8 mA; V_{CC} = 2.3 V	-		0.45	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	-	0.60	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.80	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	-	0.80	V
l _l	input leakage current	$V_{\rm I}$ = 5.5 V or GND; $V_{\rm CC}$ = 0 V to 5.5 V	-	-	±1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND;$ $V_{CC} = 5.5 \text{ V}$	-	±0.1	±2	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 5.5 V; V_{CC} = 0 V	-	-	±2	μA
I _{CC}	supply current	V _I = 5.5 V or GND; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	-	4	μA
ΔI _{CC}	additional supply current	per pin; V _I = V _{CC} - 0.6 V; V _{CC} = 2.3 V to 5.5 V; I _O = 0 A	-	-	500	μA

[1] All typical values are measured at T_{amb} = 25 °C.

11 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground 0 V); for test circuit see Figure 9.

Symbol	Parameter	Conditions	-40	°C to +85	°C	-40 °C to	+125 °C	Unit
			Min	Тур ^[1]	Max	Min	Мах	
t _{PZL}	OFF-state to LOW	nA, nB to nY; see <u>Figure 8</u>						
	propagation delay	V _{CC} = 1.65 V to 1.95 V	1.2	3.0	8.6	1.2	10.8	ns
		V_{CC} = 2.3 V to 2.7 V	0.7	1.8	4.8	0.7	6.0	ns
		V _{CC} = 2.7 V	0.7	2.5	4.4	0.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	0.7	2.1	4.1	0.7	5.2	ns
		V_{CC} = 4.5 V to 5.5 V	0.5	1.5	3.3	0.5	4.2	ns
t _{PLZ}	LOW to OFF-state	nA, nB to nY; see <u>Figure 8</u>						
	propagation delay	V _{CC} = 1.65 V to 1.95 V	1.2	3.0	8.6	1.2	10.8	ns
		V_{CC} = 2.3 V to 2.7 V	0.7	1.8	4.8	0.7	6.0	ns
		V _{CC} = 2.7 V	0.7	2.5	4.4	0.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	0.7	2.1	4.1	0.7	5.2	ns
		V_{CC} = 4.5 V to 5.5 V	0.5	1.5	3.3	0.5	4.2	ns
C _{PD}	power dissipation capacitance	per gate; V_I = GND to V_{CC} ^[2]	-	5	-	-	-	pF

Typical values are measured at nominal V_{CC} and at T_{amb} = 25 °C. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). [1]

[2]

$$\begin{split} P_{D} &= C_{PD} \; x \; V_{CC}^{2} \; x \; f_{i} \; x \; N + \sum (C_{L} \; x \; V_{CC}^{2} \; x \; f_{o}) \; \text{where:} \\ f_{i} &= \text{input frequency in MHz;} \end{split}$$

fo = output frequency in MHz;

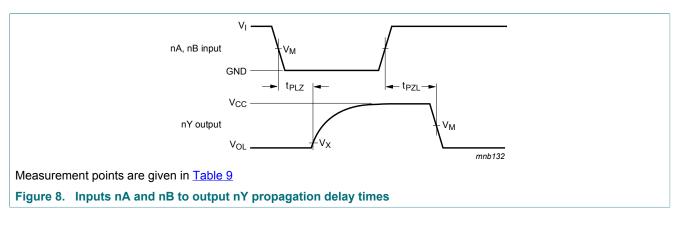
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11.1 Waveforms and test circuit



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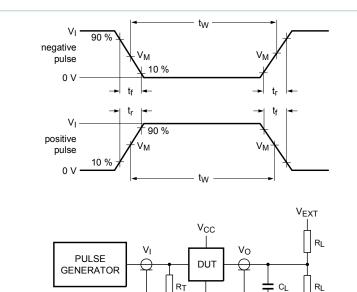
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Table 9. Measurement points

Supply voltage	Input	Output	
V _{cc}	V _M	V _X	V _M
1.65 V to 1.95 V	0.5 x V _{CC}	V _{OL} + 0.15 V	0.5 x V _{CC}
2.3 V to 2.7 V	0.5 x V _{CC}	V _{OL} + 0.15 V	0.5 x V _{CC}
2.7 V	1.5 V	V _{OL} + 0.3 V	1.5 V
3.0 V to 3.6 V	1.5 V	V _{OL} + 0.3 V	1.5 V
4.5 V to 5.5 V	0.5 x V _{CC}	V _{OL} + 0.3 V	0.5 x V _{CC}



 \mathcal{H}

Test data is given in Table 10

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Figure 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V _{EXT}
V _{cc}	VI	t _r , t _f	CL	RL	t _{PLZ} , t _{PZL}
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	2 x V _{CC}
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	2 x V _{CC}
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	6 V
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	6 V
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	2 x V _{CC}

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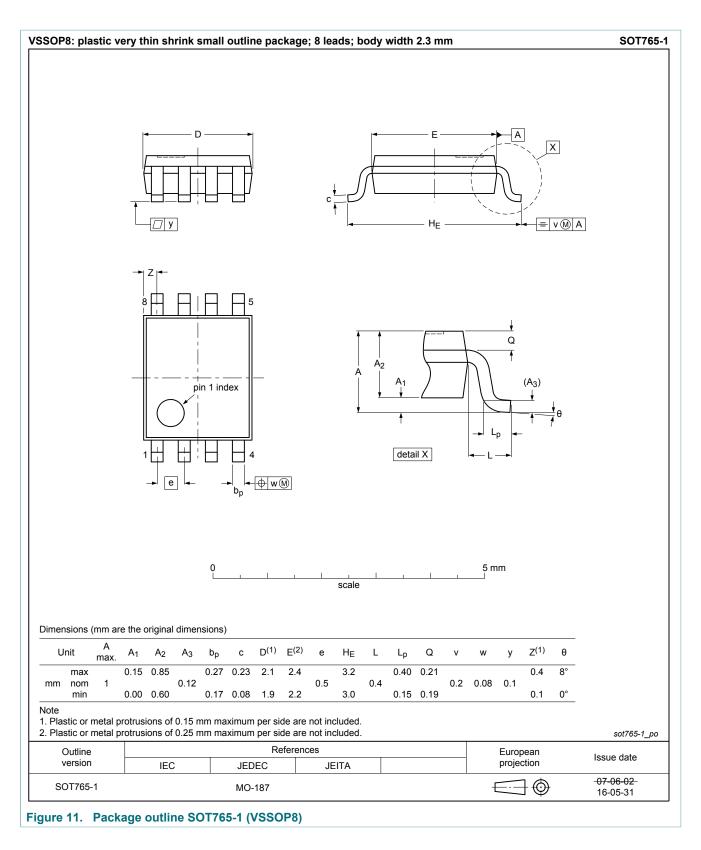
Dual 2-input NAND gate; open drain

12 Package outline

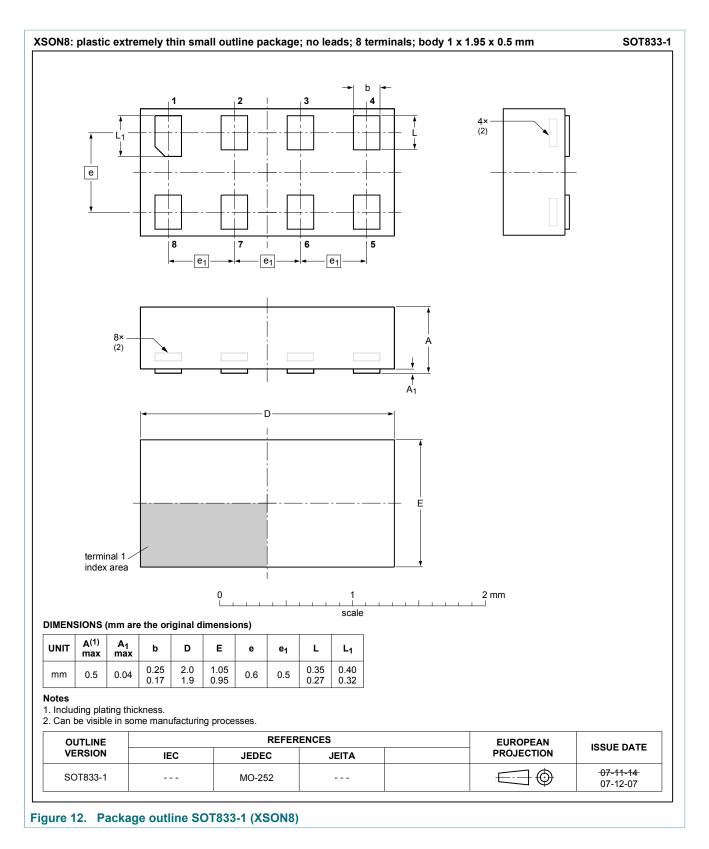
SOP8	: plas	tic th	in shr	ink sr	nall o	utline	pack	age; 8	3 lead	s; boc	ly wid	ith 3 n	nm; le	ead le	ngth (0.5 mr	n S	OT50	
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			8 1 pin	z		5	v (b)				A1 ♥ ∠	detail			(A ₃) ↓ ↓ ↓ ₽ ₽ ₽)			
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mm	1.1	0.15 0.00	0.95 0.75	0.25	0.38 0.22	0.18 0.08	3.1 2.9	3.1 2.9	0.65	4.1 3.9	0.5	0.47 0.33	0.2	0.13	0.1	0.70 0.35	8° 0°		
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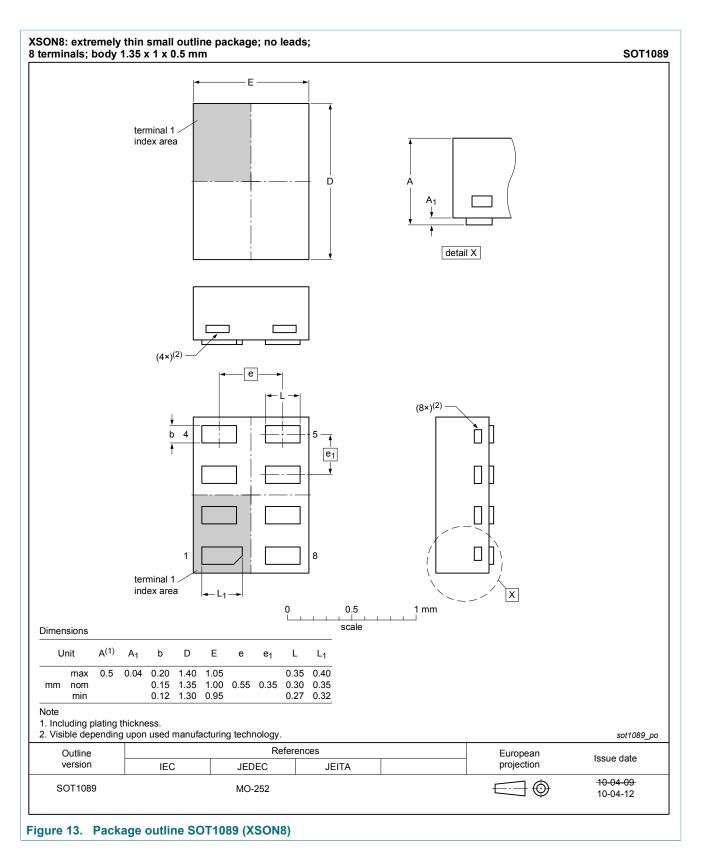
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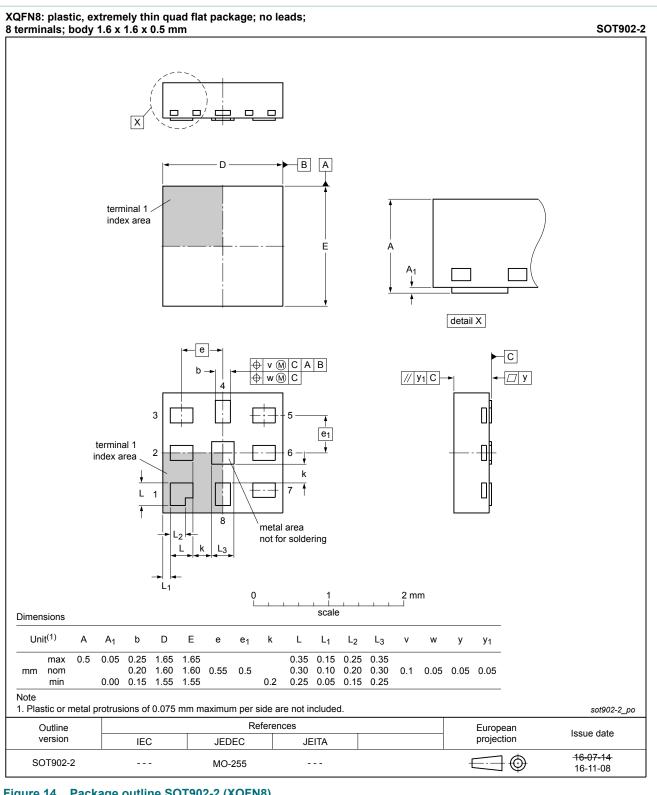
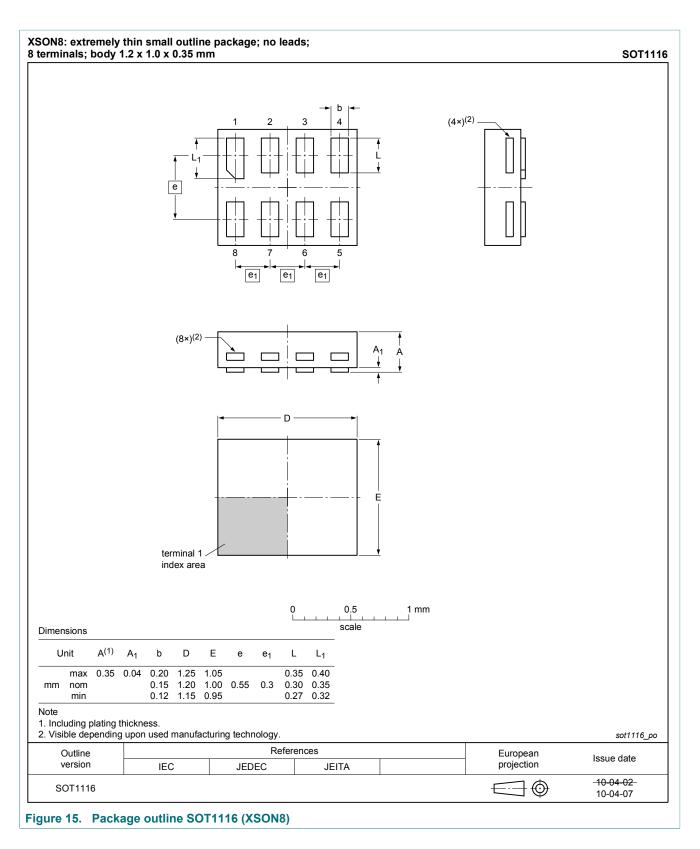
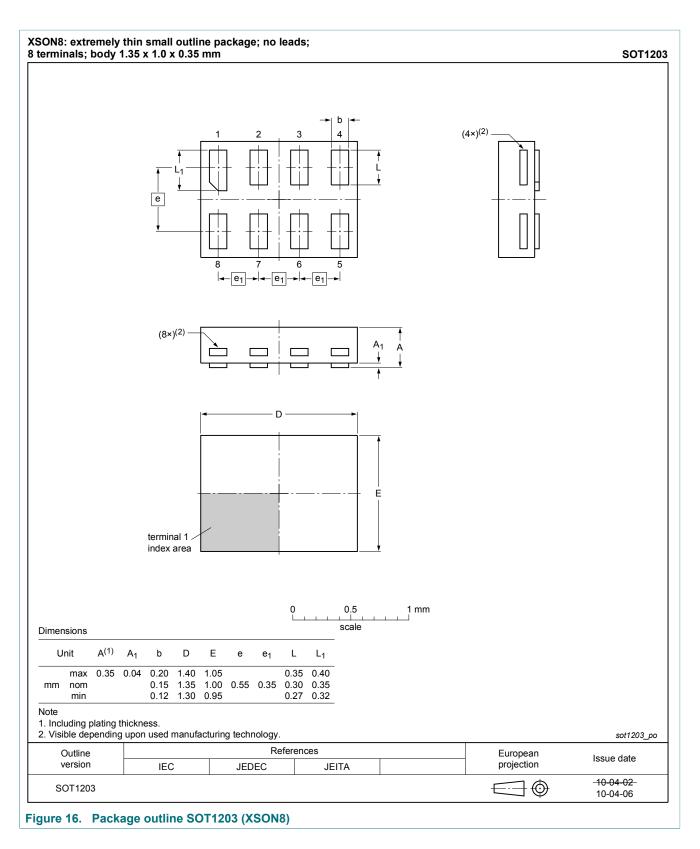


Figure 14. Package outline SOT902-2 (XQFN8)

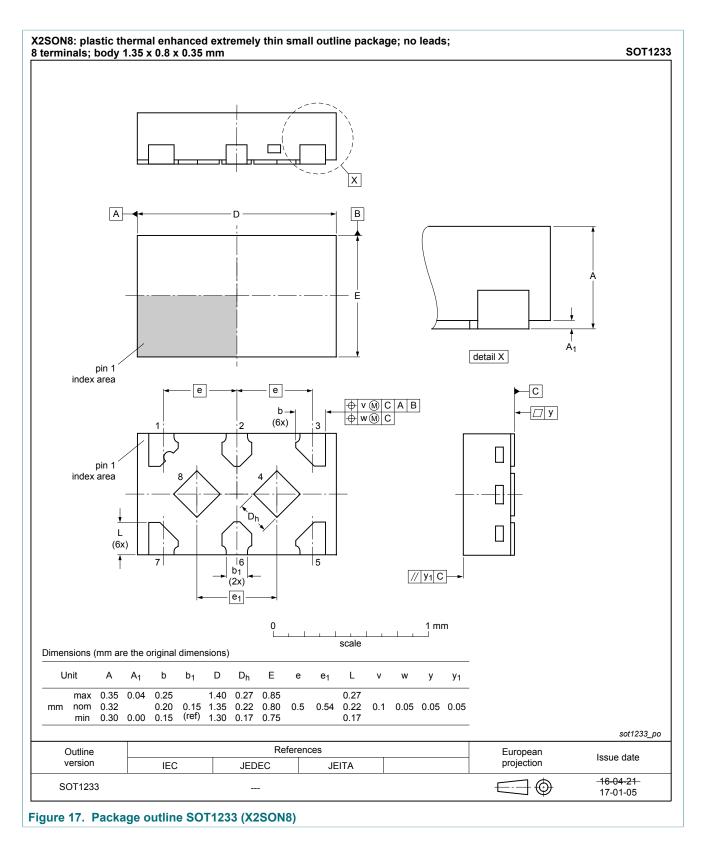
Dual 2-input NAND gate; open drain



Dual 2-input NAND gate; open drain



Dual 2-input NAND gate; open drain



13 Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
ММ	Machine Model			
TTL	Transistor-Transistor Logic			

14 Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC2G38 v.13	20170703	Product data sheet	-	74LVC2G38 v.12		
Modifications:	Nexperia. Legal texts hav Added type nur 	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Added type number 74LVC2G38GX (SOT1233 / X2SON8). Type number 74LVC2G38GD removed. 				
74LVC2G38 v.12	20161215	Product data sheet	-	74LVC2G38 v.11		
Modifications:	• <u>Table 7</u> : The m	• <u>Table 7</u> : The maximum limits for leakage current and supply current have changed.				
74LVC2G38 v.11	20130408	Product data sheet	-	74LVC2G38 v.10		
Modifications:	For type number	For type number 74LVC2G38GD XSON8U has changed to XSON8.				
74LVC2G38 v.10	20120628	Product data sheet	-	74LVC2G38 v.9		
Modifications:	For type number	• For type number 74LVC2G38GM the SOT code has changed to SOT902-2.				
74LVC2G38 v.9	20111128	Product data sheet	-	74LVC2G38 v.8		
Modifications:	 Legal pages up 	Legal pages updated.				
74LVC2G38 v.8	20101104	Product data sheet	-	74LVC2G38 v.7		
74LVC2G38 v.7	20090320	Product data sheet	-	74LVC2G38 v.6		
74LVC2G38 v.6	20080219	Product data sheet	-	74LVC2G38 v.5		
74LVC2G38 v.5	20070904	Product data sheet	-	74LVC2G38 v.4		
74LVC2G38 v.4	20060516	Product data sheet	-	74LVC2G38 v.3		
74LVC2G38 v.3	20050201	Product specification	-	74LVC2G38 v.2		
74LVC2G38 v.2	20041018	Product specification	-	74LVC2G38 v.1		
74LVC2G38 v.1	20031027	Product specification	-	-		

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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